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Supplymentary Information

Correlated migration of ions in a 2D heterostructure anode:

guaranteeing a low barrier for a high site occupancy

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Table S1. POSCAR of a Li intercalated VS_2/Ti_2CO_2 heterostructure at Occ.=1.

VS ₂ /Ti ₂ CO ₂ -Li	
1.000000000000000	
3.2388999462000001	0.00000000000000 0.00000000000000000000
-1.6178978150000001	2.805865200200000 0.000000000000000
0.00000000000000000	0.00000000000000 25.000000000000000
Ti C O S	V Li
2 1 2 2 1	1
Direct	
0.5616271129020177	0.8886529346160559 0.2240295124594188
0.2316505026101728	0.2191582673107682 0.1365415021496281
0.8979722557349076	0.5527547960702942 0.1786265584705758
0.5639021401114961	0.8838223799415655 0.0820233302126080
0.2312853023193097	0.2211076735161408 0.2704443959979262
0.5775761300617931	0.8737569450919271 0.3855990458938140
0.5782861255458963	0.8729890319350498 0.5004149919375039
0.2437851236062962	0.2075804841221945 0.4431885949724720
0.8887703824416248	0.5564356765732144 0.3083840743814751

Adhesion energy. The adhesion energy, E_{ad}^{heter} , of the TMD/MXene heterostructures can be obtained by,

$$E_{ad}^{heter} = \frac{E(Hetero) - E(MXene) - E(TMD)}{N_{hetero}},$$
(S1)

where E(MXene), E(TMD) and E(Hetero) are the free energies of the MXene, TMD and the compositive heterostructure, respectively, and N_{hetero} is the ion number in the heterostructure. Obviously, a lower E_{ad}^{heter} indicates a more stable stacking pattern. Then, the adhesion energies of alkali metals loaded on a heterostructure is shown as,

$$E_{ad}^{ion} = \frac{E(Hetero + N_{ion}alkali) - E(Hetero) - N_{ion}E(alkali)}{N_{ion}},$$
(S2)

where N_{ion} is number of alkali metals on the heterostructure, and $E(\text{Hetero}+N_{ion}\text{alkali})$ and $N_{ion}E(\text{alkali})$ are the free energy of the heterostructure with N_{ion} alkali and the free energy of the N_{ion} alkali in their bulk structures.



Fgiure S1. (a) Stable stacking pattern of VS₂ and Ti_2CO_2 used in the present study, (b) intercalated sites of Li ions in the heterojunction after geometry optimization, and (c) charge density isosurfaces of 0.03 (blue) and 0.01 (green) e/bohr³ in the Li intercalated heterojunction are displayed, where the line with two black points indicates the atoms at both ends have same *x*- and *y*-coordinates.



Fgirue S2. (a) Comparison of the lattice parameter of single layer VS₂ from PBE+U with experimental value of 3.22 Å in Ref.¹, from which we choose U_{eff} =2.5 eV, and (b) comparison of Li adhesion energy obtained from PBE+U and PBE, and almost consistent values are found.



Figure S3. Comparison of adhesion energies, E_{ad} , for Li ion in the stable site (S₁) and in two unstable sites (S₁', S₁") in diffusion path. S₁' is in the middle of S₁ and S₂, and S₁" is directly facing (has same x-and y-coordinates with) an O atom in the Ti₂CO₂.



Figure S4. Polyhedral plots for the (a) heterostructure, (b) only VS_2 and (c) only Ti_2CO_2 with Li diffusion path.



Figure S5. (a) Interface of Li (1 1 0) face and VS_2/Ti_2CO_2 heterostructure and the intercalating path for a Li atom from the Li crystal to an intercalation site, and (b) the corresponding energy profile. When preforming the CI-NEB calculation, other atoms (except the mobile ion) are fixed.



Figure S6. Li probability density isosurfaces for the Li intercalated 4×4 supercell of VS₂/Ti₂CO₂ at 900 K, where density value *p* is set as 0.015 and 0.008 for a and b. In a, we found Li ions mainly stay around the stable sites S and sometimes around the metastable site S'', which is consistent with the geometry optimization result. Then, when decreasing the density value, the main

diffusion path, from S to S" then to S, is clearly shown in b, which verifies the lowest barrier path from CI-NEB calculations.

Discussions for Fig. S7. Fig. S7a shows that unoccupied Li sites are the mediums for ion migration. If Occ.~1 (i.e. there are very few unoccupied sites), the lack of diffusion medium may hinder the correlated migrations. However, in a practical 2D heterostructure anode, the adhesion energy, E_{ad} , of Li ion can gradually increase with site occupancy, as shown in Fig. S7b. Such as in reference², the authors found that Li average adhesion energy (they called binding energy) in Sc₂C(OH)₂/graphene heterostructure increases from ~-0.9 eV at ~0.11 Occ. (they called concentration) to ~0 eV at ~0.75 Occ., which means new Li ions will not continue to intercalate in the heterostructure when Occ.>0.75 due to the weak adhesion. Similarly, reference³ shows that the adhesion energies of Na, Ca and K ions in Ti₂CO₂/graphene also significantly increase with Occ. and become very close to 0 eV, indicating weak adhesions at high ion site occupancy.

In Fig. S7b, the gap between Occ. of E_{ad} ~0 to 1 is we mentioned "gap to 1". When E_{ad} >0, ions trend to form the Li crystal due to the lower energy other than entering the heterostructure, as shown in Fig. S7c. Because of the "gap to 1", there should be some unoccupied sites for the correlated migrations of Li in most cases.



Figure S7. (a) Unoccupied Li sites as the mediums for ion migration. (b) Adhesion energy, E_{ad} , of intercalated ions gradually increasing with site occupancy and when when E_{ad} reaches to 0, the gap between Occ. to 1 is we mentioned "gap to 1". (c) Effect of E_{ad} on the intercaliton of ions, where if $E_{ad} < 0$ ions trend to be intercalated into the heterostructure, and if $E_{ad} > 0$ ions trend to form the Li crystal due to the lower energy other than entering the heterostructure.

References

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